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GRF2501

High Gain, Ultra-LNA 802.11ac: 4.9—6.0 GHz



Features

Reference: 3.3V/15mA/5.5 GHz

De-embedded NF: 0.8 dB

Gain: 16.0 dB

IP1dB: -8.0 dBm

- Flexible Bias Voltage and Current
- Internally Matched to 50 Ω
- Process: GaAs pHEMT

Applications

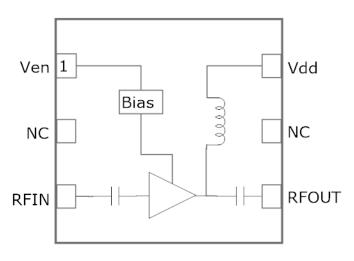
- WiFi Access Points
- Mobile WiFi Devices
- 802.11p Vehicle Communications
- Microwave Backhaul

Product Description

GRF2501 is an ultra-low noise amplifier (LNA) designed for IEEE 802.11a/n/ac/p applications (5.1 GHz to 5.925 GHz). Over this band, the device exhibits outstanding deembedded noise figure (NF) of 0.80 dB along with excellent gain flatness. The high gain, superior NF and directivity of its design allows designers to create receiver architectures with outstanding cascaded NF and unconditional stability.

The LNA is operated from a single positive supply of 2.7 to 5.0 V with a typical bias condition of 3.3 V and 15 mA. GRF2501 is internally matched to 50 Ω at the input and output ports.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device sparameters.



1.5 x 1.5 mm DFN-6



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Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	V _{DD}	0	6.0	V
RF Input Power: (Load VSWR < 2:1; V _D : 5.0 volts)	P _{IN MAX}		15	dBm
Operating Temperature (Package Heat Sink)	Т _{АМВ}	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	P _{DISS MAX}		200	mW
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	НВМ	250		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	

Caution! ESD Sensitive Device





Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

Note: For package dimensions and manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2501 landing page: Manufacturing Note-MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

Link to manufacturing note

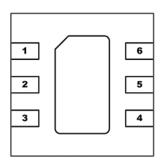
Revision Date: 02/28/18



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Pin Out (Top View)



Pin Assignments:

Pin	Name	Description	Note		
1	VENABLE	LNA Enable Input	$\label{eq:Venable} \begin{tabular}{ll} V_{\text{ENABLE}} & = 0.2 \ \text{volts disables device.} \ Ondie \ pull-down \ resistor \ will \ turn \ the \ part \ off \ if \ this \ node \ is \ allowed \ to \ float. \end{tabular}$		
2	NC	No Connect or Ground	No internal connection to die		
3	RF_In	LNA RF input	Internally matched to 50 Ω . These ports may be DC connected to ground		
4	RF_Out	LNA RF output	externally but no DC > 0.2 volts should be applied to these ports.		
5	NC	No Connect or Ground	No internal connection to die		
6	$V_{ exttt{DD}}$	Supply Voltage for the LNA	Requires bypass capacitance as close as possible to pin on PCB		
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recommend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.		

VENABLE Truth Table:

Revision Date: 02/28/18

V_{DD}	V _{ENABLE}	Mode
High	>=1.8 V	LNA On
High	<0.1 V	LNA Off



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Nominal Operating Parameters:

Parameter	Symbol	Specification			Unit	Condition
	Syllibol	Min. Typ. Max.	Ullit			
High Gain Mode						V _{DD} = 3.3 V, V _{ENABLE} = 3.3 V, T _A = 25 °C
Test Frequency	F _{TEST}		5500		MHz	
Gain	S21	15.0	16.0		dB	
Gain Flatness	ΔS21		+/- 0.5		dB	Across 5.1 to 5.825 GHz
Evaluation Board Noise Figure	NF		1.1	1.3	dB	
Input Power at 1% EVM	EVM		-19.0		dBm	802.11a modulation
Input 1dB Compression	IP1dB	-10.0	-8.0		dBm	
Supply Current (Quiescent)	I _{DD}	12.0	15.0	28.0	mA	
Enable Current	I _{ENABLE}		1.5	3.0	mA	
Disabled Mode						V _{DD} = 3.3 V, V _{ENABLE} = 0.0V
Supply Current (Leakage)	I _{DD}		200	500	μА	
Thermal Data						
Thermal Resistance (Infra-Red Scan)	Θјс		150		°C/W	
Channel Temperature @ +85 C reference (Package heat sink)	T _{CHANNEL}		99		оC	Vdd: 3.3V; Iddq: 28 mA; No RF Pdiss: 92 mW

GRF2501 Evaluation Board Performance Summary Table:

Revision Date: 02/28/18

Tune (GHz)	Reference Freq. (GHz)	Gain (dB)	NF (dB) (de-embedded)	IP1dB (dBm)	Input Power for 1% EVM (dBm)	Bias Condition (V/mA)
4.9 to 6.0	5.1	16.2	0.75	-8.7	-20.0	3.3/15
4.9 to 6.0	5.5	16.0	0.80	-8.0	-19.0	3.3/15
4.9 to 6.0	5.9	15.8	0.80	-7.7	-19.0	3.3/15

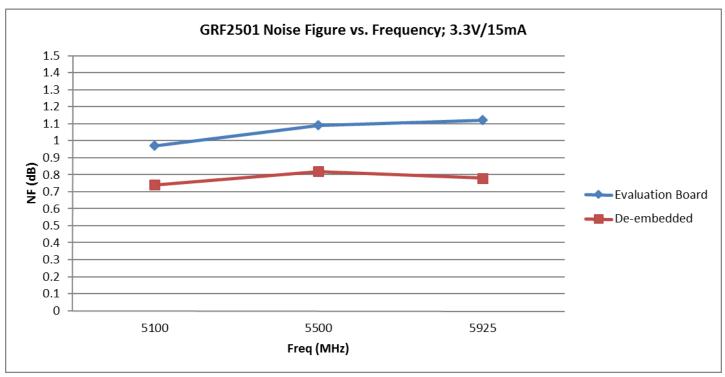


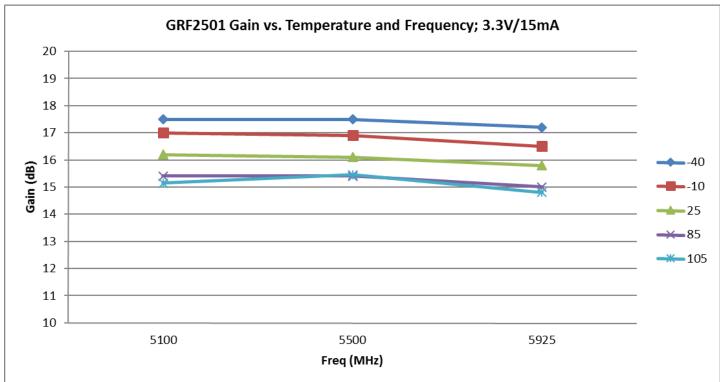
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GRF2501 Evaluation Board Measured Data:





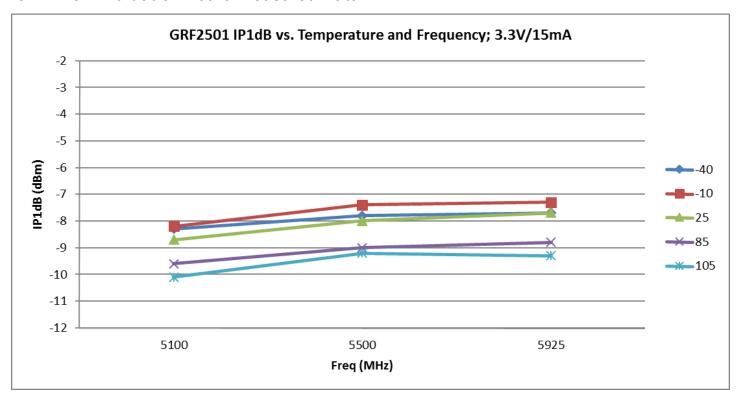


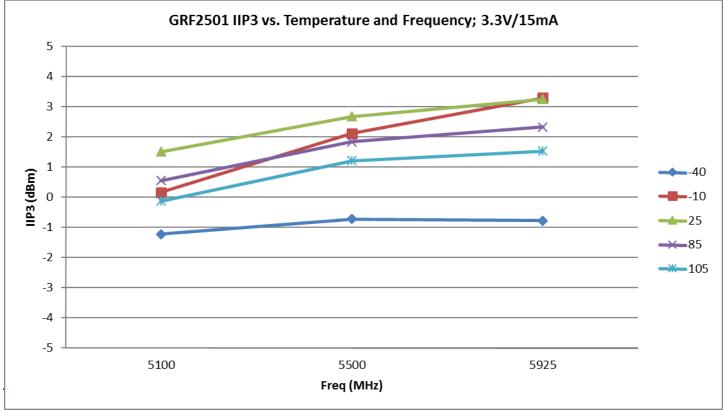
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GRF2501 Evaluation Board Measured Data:





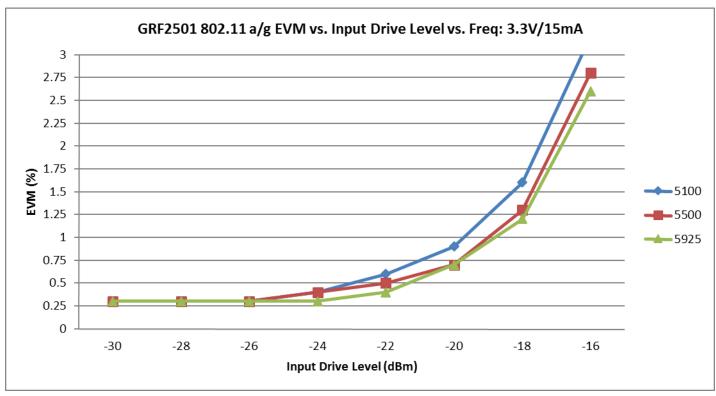


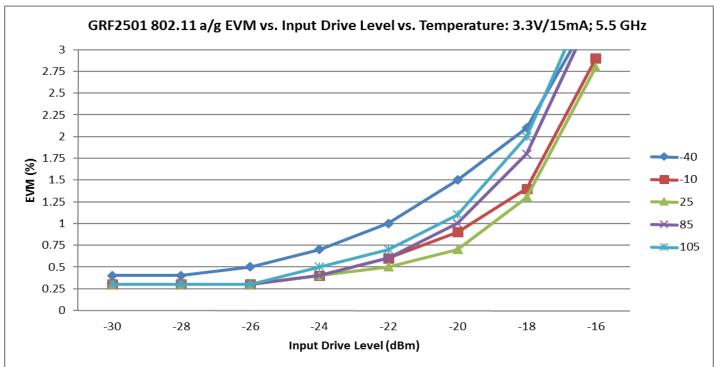
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GRF2501 Evaluation Board Measured Data:





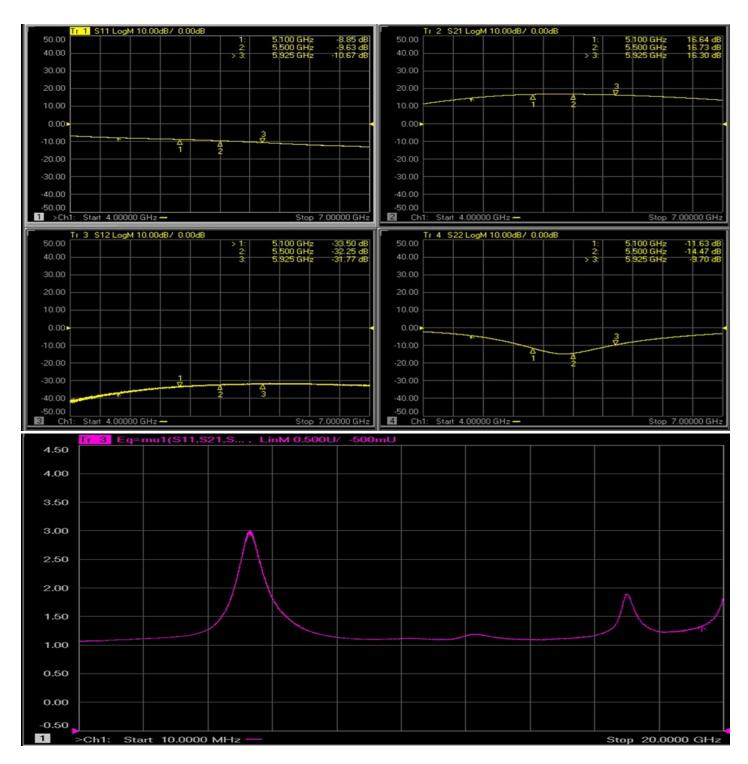


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GRF2501 Evaluation Board S-Pars:



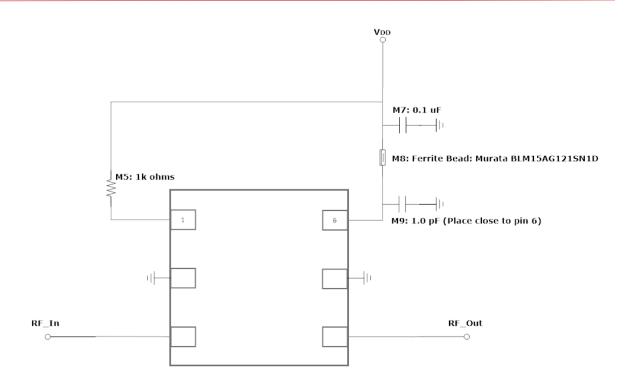
Note: Mu >= 1.0 implies unconditional stability



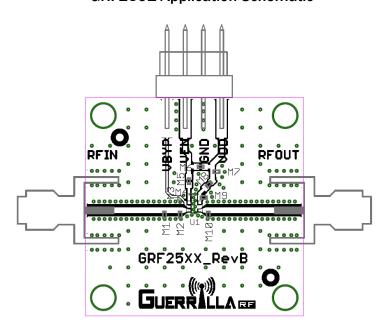
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GRF2501 Application Schematic



GRF2501 Evaluation Board Assembly Diagram



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Data Sheet Release Status:	Notes
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on device size, bias condition and experience with related devices.
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.

Information in this datasheet is specific to the Guerrilla RF, Inc. ("Guerrilla RF") product identified.

Revision Date: 02/28/18

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Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,

Промышленная ул, дом № 19, литера Н,

помещение 100-Н Офис 331